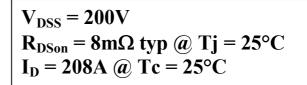
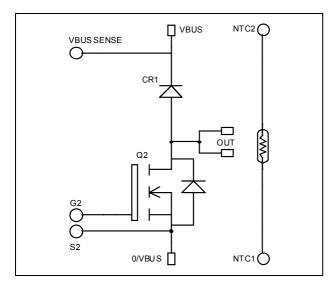


Boost chopper MOSFET Power Module





G2 🛭

S2 🛱

G2 0

OUT

NTC2

NTC1

O/VBUS

Application

- AC and DC motor control
- Switched Mode Power Supplies
- Power Factor Correction

Features

- Power MOS 7[®] MOSFETs
 - Low R_{DSon}
 - Low input and Miller capacitance
 - Low gate charge
 - Avalanche energy rated
 - Very rugged
- Kelvin source for easy drive
- Very low stray inductance
 - Symmetrical design
 - Lead frames for power connections
- Internal thermistor for temperature monitoring
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- RoHS compliant

Absolute maximum ratings

0

VBUS

⋒ ∨BUS

Symbol	Parameter		Max ratings	Unit
$V_{ m DSS}$	Drain - Source Breakdown Voltage		200	V
T	Continuous Drain Current	$T_c = 25$ °C	208	
I_D	Continuous Drain Current	$T_c = 80^{\circ}C$	155	A
I_{DM}	Pulsed Drain current	Ised Drain current		
V_{GS}	Gate - Source Voltage		±30	V
R _{DSon}	Drain - Source ON Resistance		10	mΩ
P_{D}	Maximum Power Dissipation $T_c = 25^{\circ}C$		781	W
I_{AR}	Avalanche current (repetitive and non repetitive)		100	A
E_{AR}	Repetitive Avalanche Energy		50	mJ
E_{AS}	Single Pulse Avalanche Energy		3000	1113

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25^{\circ}C$ unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
Ţ	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 200V$ $T_j = 25^{\circ}C$			150	^
$I_{ m DSS}$		$V_{GS} = 0V, V_{DS} = 160V$ $T_j = 125^{\circ}C$			750	μА
R _{DS(on)}	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 104A$		8	10	mΩ
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 5mA$	3		5	V
I_{GSS}	Gate – Source Leakage Current	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$			±150	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
C_{iss}	Input Capacitance	$V_{GS} = 0V$		14.4		
C_{oss}	Output Capacitance	$V_{DS} = 25V$		4.66		nF
C_{rss}	Reverse Transfer Capacitance	f = 1MHz		0.29		
Q_{g}	Total gate Charge	$V_{GS} = 10V$		280		
Q_{gs}	Gate – Source Charge	$V_{Bus} = 100V$		106		nC
Q_{gd}	Gate – Drain Charge	$I_D = 208A$		134		
$T_{d(on)}$	Turn-on Delay Time	Inductive switching @ 125°C		32		ns
$T_{\rm r}$	Rise Time	$V_{GS} = 15V$		64		
$T_{d(off)}$	Turn-off Delay Time	$\begin{split} V_{Bus} &= 133V \\ I_D &= 208A \\ R_G &= 2.5\Omega \end{split}$		88		
T_{f}	Fall Time			116		
Eon	Turn-on Switching Energy	Inductive switching @ 25°C $V_{GS} = 15V$, $V_{Bus} = 133V$ $I_D = 208A$, $R_G = 2.5\Omega$		1698		т
$\mathrm{E}_{\mathrm{off}}$	Turn-off Switching Energy			1858		μJ
Eon	Turn-on Switching Energy	Inductive switching @ 125°C $V_{GS} = 15V$, $V_{Bus} = 133V$ $I_D = 208A$, $R_G = 2.5\Omega$		1872		
E _{off}	Turn-off Switching Energy			1972		μJ

Chopper diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			200			V
I _{RM} Maximum Reverse Leakage Current	$V_R=200V$	$T_j = 25$ °C			500	μΑ	
			$T_j = 125$ °C		400	750	
I_F	DC Forward Current		$T_c = 80^{\circ}C$		180		Α
	Diode Forward Voltage	$I_{\rm F} = 180A$			1.1	1.15	
$V_{\rm F}$		$I_{\rm F} = 360 A$			1.4		V
		$I_F = 180A$	$T_j = 125^{\circ}C$		0.9		
f	Reverse Recovery Time	$T_j = 25^\circ$	$T_j = 25^{\circ}C$		31		ns
t _{rr}	Reverse Recovery Time	$I_F = 180A$	$T_j = 125$ °C		60		115
Q _{rr}	Reverse Recovery Charge	$V_R = 133V$ $di/dt = 600A/\mu s$	$T_j = 25$ °C		180		пС
			$T_j = 125$ °C		750		iic



Thermal and package characteristics

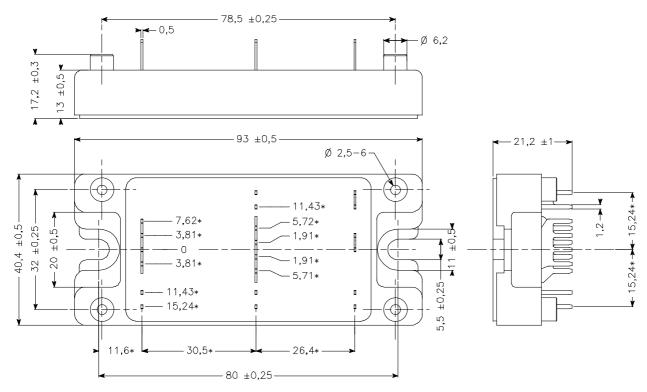
Symbol	Characteristic			Min	Typ	Max	Unit
D	Junction to Case Thermal Resistance		Transistor			0.16	°C/W
R_{thJC}			Diode			0.32	C/ VV
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range			-40		150	
T_{STG}	Storage Temperature Range		-40		125	°C	
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To Heatsink	M5	2.5		4.7	N.m
Wt	Package Weight					160	g

Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

Symbol	Characteristic	Min	Тур	Max	Unit
R ₂₅	Resistance @ 25°C		50		kΩ
${ m B}_{25/85}$	$T_{25} = 298.15 \text{ K}$		3952		K

$$R_{T} = \frac{R_{25}}{\exp\left[B_{25/85}\left(\frac{1}{T_{25}} - \frac{1}{T}\right)\right]}$$
 T: Thermistor temperature R_T: Thermistor value at T

SP4 Package outline (dimensions in mm)

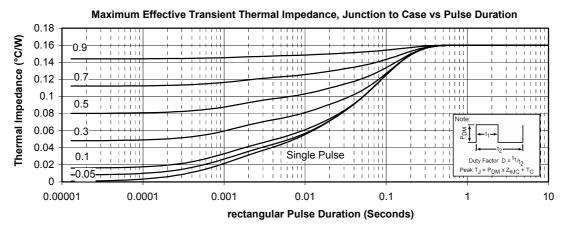


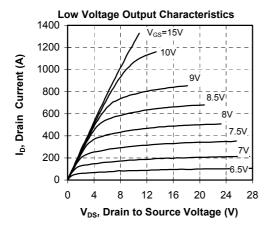
ALL DIMENSIONS MARKED " * " ARE TOLERENCED AS : $\boxed{\oplus \varnothing 1}$

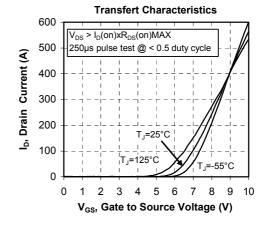
See application note APT0501 - Mounting Instructions for SP4 Power Modules on www.microsemi.com

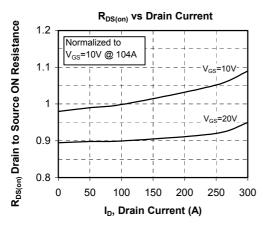


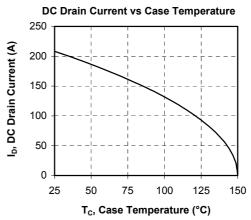
Typical Performance Curve





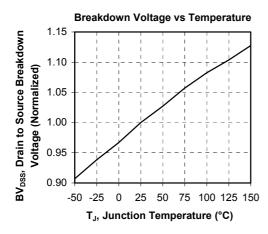


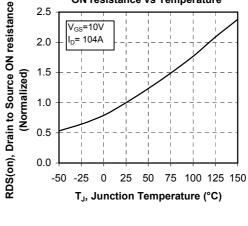


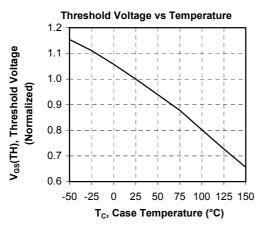


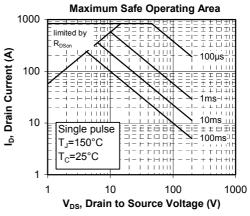


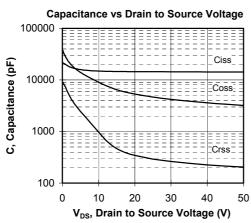
ON resistance vs Temperature

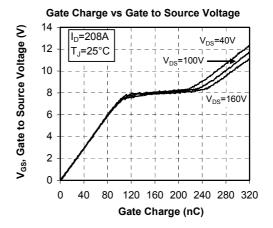




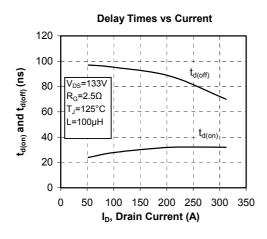


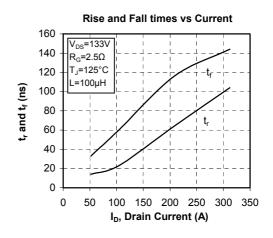


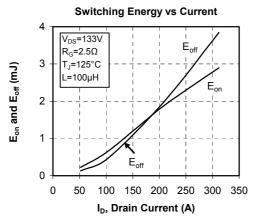


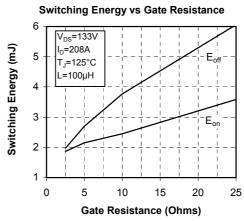


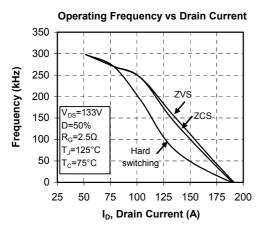


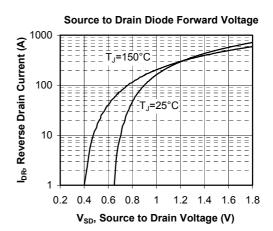












DISCLAIMER

The information contained in the document (unless it is publicly available on the Web without access restrictions) is PROPRIETARY AND CONFIDENTIAL information of Microsemi and cannot be copied, published, uploaded, posted, transmitted, distributed or disclosed or used without the express duly signed written consent of Microsemi. If the recipient of this document has entered into a disclosure agreement with Microsemi, then the terms of such Agreement will also apply. This document and the information contained herein may not be modified, by any person other than authorized personnel of Microsemi. No license under any patent, copyright, trade secret or other intellectual property right is granted to or conferred upon you by disclosure or delivery of the information, either expressly, by implication, inducement, estoppels or otherwise. Any license under such intellectual property rights must be approved by Microsemi in writing signed by an officer of Microsemi.

Microsemi reserves the right to change the configuration, functionality and performance of its products at anytime without any notice. This product has been subject to limited testing and should not be used in conjunction with life-support or other mission-critical equipment or applications. Microsemi assumes no liability whatsoever, and Microsemi disclaims any express or implied warranty, relating to sale and/or use of Microsemi products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright or other intellectual property right. Any performance specifications believed to be reliable but are not verified and customer or user must conduct and complete all performance and other testing of this product as well as any user or customers final application. User or customer shall not rely on any data and performance specifications or parameters provided by Microsemi. It is the customer's and user's responsibility to independently determine suitability of any Microsemi product and to test and verify the same. The information contained herein is provided "AS IS, WHERE IS" and with all faults, and the entire risk associated with such information is entirely with the User. Microsemi specifically disclaims any liability of any kind including for consequential, incidental and punitive damages as well as lost profit. The product is subject to other terms and conditions which can be located on the web at http://www.microsemi.com/legal/tnc.asp

Life Support Application

Seller's Products are not designed, intended, or authorized for use as components in systems intended for space, aviation, surgical implant into the body, in other applications intended to support or sustain life, or for any other application in which the failure of the Seller's Product could create a situation where personal injury, death or property damage or loss may occur (collectively "Life Support Applications").

Buyer agrees not to use Products in any Life Support Applications and to the extent it does it shall conduct extensive testing of the Product in such applications and further agrees to indemnify and hold Seller, and its officers, employees, subsidiaries, affiliates, agents, sales representatives and distributors harmless against all claims, costs, damages and expenses, and attorneys' fees and costs arising, directly or directly, out of any claims of personal injury, death, damage or otherwise associated with the use of the goods in Life Support Applications, even if such claim includes allegations that Seller was negligent regarding the design or manufacture of the goods.

Buyer must notify Seller in writing before using Seller's Products in Life Support Applications. Seller will study with Buyer alternative solutions to meet Buyer application specification based on Sellers sales conditions applicable for the new proposed specific part.